

October 2013

# S1A - S1M General Purpose Rectifiers

### **Features**

- 1 AI<sub>F(AV)</sub> Current Rating
- Glass Passivated
- · Low Leakage:
  - 1 μA Maximum at 25°C
  - 50 μA Maximum at 125°C
- Fast Response: 1.8 μs (Typical)
- 30 A Surge Rating
- 50 to 1000 V Reverse Voltage Ratings
- 6.6 pF Typical Capacitance
- RoHS Compliant

## **Description**

In the world of commodity rectifiers, Fairchild Semiconductor's S1 family of 1 A, P-I-N, SMA rectifiers stand out for their optimized low leakage, low capacitance, and fast response time. This was achieved while maintaining the industry standard  $V_F$  max of 1.1 V at 1 A and a 30 A surge rating. In today's world, where system power efficiency is a critical differentiating feature, these advantages can be leveraged to support those higher efficiency goals.



## **Ordering Information**

Part Number	Marking	Package	Packing Method	
S1A	S1A	DO-214AC Tape and Re		
S1B	S1B	DO-214AC	Tape and Reel	
S1D	S1D	DO-214AC	Tape and Reel	
S1G	S1G	DO-214AC	AC Tape and Reel	
S1J	S1J	DO-214AC	O-214AC Tape and Reel	
S1K	S1K	DO-214AC	14AC Tape and Reel	
S1M	S1M	DO-214AC	DO-214AC Tape and Reel	

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## **Absolute Maximum Ratings**(1)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value						Units	
Symbol	Farameter		1B	1D	1G	1J	1K	1M	Uiilis
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage		100	200	400	600	800	1000	V
I <sub>F(AV)</sub>	Average Rectified Forward Current at T <sub>A</sub> = 100°C		1.0					Α	
I <sub>FSM</sub>	Non-Repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave		30						Α
T <sub>STG</sub>	Storage Temperature Range		-55 to +150					°C	
$T_J$	Operating Junction Temperature		-55 to +150				·	°C	

#### Note:

## **Thermal Characteristics**

Symbol	Parameter	Max.	Units
$P_{D}$	Power Dissipation	1.4	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient <sup>(2)</sup>	85	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient <sup>(3)</sup>	170	°C/W
Ψ <sub>jl</sub>	Junction-Lead thermal characteristics <sup>(3)</sup>	25	°C/W

### Notes:

- 2. Device mounted on FR-4 PCB, land pattern size: 25 mm<sup>2</sup> (5 x 5 mm).
- 3. Device mounted on FR-4 PCB, land pattern size: 4.6375 mm<sup>2</sup> (2.65 x 1.75 mm).

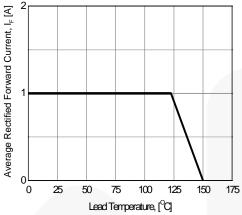
## **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Parameter Test Condition		Max.	Units
$V_{F}$	Forward Voltage	I <sub>F =</sub> 1.0 A		1.1	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A	1.8		μs
I <sub>R</sub>	Reverse Current at Rated V <sub>R</sub>	$T_{A} = 25^{\circ}C$ $T_{A} = 125^{\circ}C$		1.0 50	μA μA
C <sub>T</sub>	Junction Capacitance	V <sub>R</sub> = 4.0 V, f = 1.0MHz	6.6		pF

<sup>1.</sup> These ratings are limiting values above which the serviceability of any semiconductor device maybe impaired.

## **Typical Performance Characteristics**



**Figure 1. Forward Current Derating Curve** 

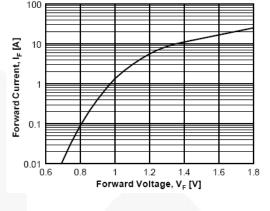


Figure 2. Forward Voltage Characteristics

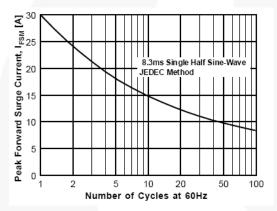


Figure 3. Non-Repetitive Surge Current

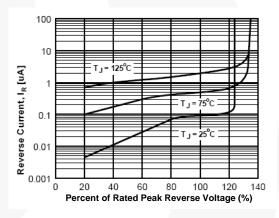


Figure 4. Reverse Current vs. Reverse Voltage

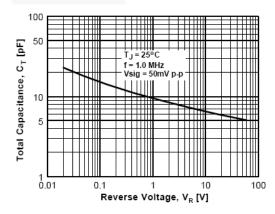
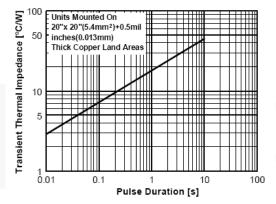


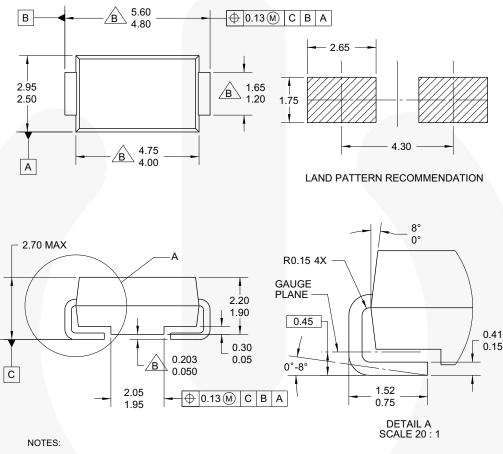
Figure 5. Total Capacitance



**Figure 6. Thermal Impedance Characteristics** 

## **Physical Dimension**

## **DO-214AC**



- A. EXCEPT WHERE NOTED CONFORMS TO JEDEC DO214 VARIATION AC.

  B. DOES NOT COMPLY JEDEC STD. VALUE.
  C. ALL DIMENSIONS ARE IN MILLIMETERS.
  D. DIMENSIONS ARE EXCLUSIVE OF BURRS,
  MOLD FLASH AND TIE BAR PROTRUSIONS.
- E. DIMENSION AND TOLERANCE AS PER ASME
- Y14.5-1994. F. LAND PATTERN STD. DIOM5025X231M. G. DRAWING FILE NAME: DO214ACREV1

### Figure 7. 2-LEAD, SMA, JEDEC DO-214, VARIATION AC

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Green FPS™ e-Series™ CorePOWER™

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